

# 微電腦型頻率隔離雙輸出傳送器

( DUAL OUTPUT MICROPROCESS FREQUENCY ISOLATED TRANSMITTER )

MODEL  
DTMF

CE



## ■特點(FEATURES)

- 精確度0.03%滿刻度 (Accuracy 0.03%F.S.)
- 頻率輸入範圍0.01Hz至80KHz(Input range from 0.01 Hz to 80KHz)
- 16 BIT 隔離類比輸出(16 bit DAC isolating analog output)
- 輸入/輸出1/輸出2絕緣耐壓2仟伏特/1分鐘(Dielectric strength 2KVac/1min. (input/output1/output2/power))
- 寬範圍交直流兩用電源設計(Wide input range for auxiliary power)
- 尺寸小,穩定性高(Dimension small and High stability)

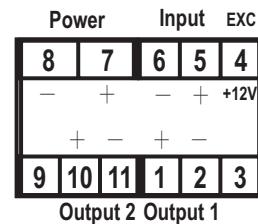
## 1.MODEL:DTMF-□ □ □ □ (選購型號)

NO	Input Type	NO	Input Type	NO	Input Type	NO	Output 1	NO	Output 1	NO	Output 2	NO	Output 2	NO	Aux. Power
1	Dry contact	5	Magnetic pick-up (AC50mV~1.5V)	7	AC2~60V	A	0~50mV	F	0~1mA	A	0~50mV	F	0~1mA	A	AC/DC 18~60V
2	Pulse(TTL)(5V)	9	SPECIFIED	C	1~5V	H	0~20mA	C	1~5V	H	0~20mA	B	AC/DC 90~260V		
3	Pulse(NPN)(12V)	6	Magnetic pick-up (AC500mV~15V)	D	0~10V	I	4~20mA	D	0~10V	I	4~20mA				*Less 4VA for AC/DC input
4	Pulse(PNP)(12V)			E	2~10V	R	SPECIFIED	E	2~10V	R	SPECIFIED				

## 2.SPCIFICATION (主要規格)

- Measuring accuracy : 0.03% F.S. (23±5°C)  
(精確度)
- Count input type : Switch selectable current sourcing(NPN) or current sinking (PNP)  
(脈波輸入型式)
- Count input trigger levels : HI bias (CMOS) ( $V_{IH}=7.5V$ ,  $V_{IL}=5.5V$ )  
LO bias (TTL) ( $V_{IH}=3.7V$ ,  $V_{IL}=2.0V$ )  
(脈波觸發電位)
- Sampling time : 20 cycles/sec. (>10Hz)  
f/2 cycles/sec(<10Hz)  
(取樣時間)
- Analog output resolution : 16 bit DAC  
(類比輸出解析度)
- Response time : <250ms (0~90%)  
(輸出反應時間)
- Output drive capability : <10mA for voltage mode  
<10V for current mode  
(輸出負載能力)
- Output ripple(p-p) : <0.1% F.S.  
(輸出漣波)
- Zero (offset) range : 0~±9999 Digit adjustable(output1)  
0~±5% F.S.(output2)  
(歸零調整範圍)
- Span (scale) range : 0~±9999 Digit adjustable(output2)  
0~±10% F.S.(output2)  
(最大值調整範圍)
- Sensor power supply : 12VDC±3% (<50mA)  
(感應器電源)
- Temp. coefficient : 50ppm/°C (0~50°C)  
(溫度係數)
- Display : Red high efficiency LEDs high 10.16mm (0.4")  
(顯示幕)
- Isolation : Input/Output1/Output2/Power/Case  
(隔離特性)
- Parameter setting : Touch switches  
(參數設定方式)
- Memory mode : Non-volatile E<sup>2</sup> PROM memory  
(記憶方式)
- Insulation Resistance : >100M ohm with 500V DC  
(絕緣阻抗)
- Dielectric strength : 2KVac/1 min. (input/output1/output2/power)  
1600Vdc (input/output1/output2)  
(絕緣耐壓能力)
- Operating condition : 0~60°C (20 to 90% RH non-condensed)  
(使用環境條件)
- Storage condition : 0~70°C (20 to 90% RH non-condensed)  
(存放環境條件)
- Construction : Socket/plugin type with barrier terminals  
(安裝方式)
- CE EMC Certification : EN 55022:1998/A1:2000 Class A  
(CE 認證)
- EN 61000-3-2:2000
- EN 61000-3-3:1995/A1:2001
- EN 55024:1998/A1:2001

## 3.TERMINAL CONNECTION (接線圖)



## 4.DIMENSION (unit:mm) (外型尺寸)

